NSN 5961-01-020-2732

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Inclosure Material:

Plastic

Overall Length:

0.400 inches

Overall Height:

0.190 inches

Overall Width:

0.315 inches

Mounting Facility Quantity:

1

Internal Configuration:

Junction contact

Mounting Method:

Unthreaded hole

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

50.0 breakdown voltage, collector-to-base, emitter open and 50.0 breakdown voltage, collector-to-emitter, base open and 13.0 breakdown voltage, emitter-to-base, collector open

Current Rating Per Characteristic:

1.50 amperes source cutoff current

Power Rating Per Characteristic:

10.0 watts small-signal input power, common-collector

Maximum Operating Tempurature Per Measurement Point:

165.0 degrees celsius junction

Special Features:

Junction pattern arrangement: npn

Terminal Type And Quantity:

3 uninsulated wire lead

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

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